Influence of Ce\(^{3+}\) polarons on grain boundary space-charge in proton conducting Y-doped BaCeO\(_3\)

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Defect segregation and space-charge formation were investigated for a \(\{0 2 1\}[1 0 0]\) symmetric tilt grain boundary in Y-doped BaCeO\(_3\). Density functional theory calculations according to the PBE+U formalism were used to calculate segregation energies for protons, oxygen vacancies and Y-acceptor dopants from the bulk to the grain boundary core. Defect concentration and potential profiles across the grain boundary were obtained from thermodynamic space-charge models. Oxygen vacancies were found to exhibit a particularly exothermic segregation energy of up to \(-1.66\) eV while protons exhibited segregation energies in the range of \(-0.47\) eV to \(-0.93\) eV. The grain boundary was determined to be predominated by protons below 800 K in 3% \(H_2O\) and the corresponding space-charge potential was 0.4–0.7 V under the Mott–Schottky approximation. The role of electronic defects in the space-charge properties was evaluated, and it was substantiated that electron conduction along the grain boundary could become evident under reducing conditions.

1. Introduction

Proton conducting ceramics within the acceptor doped BaZrO\(_3\)–BaCeO\(_3\) system exhibit excellent ionic conductivity at intermediate temperatures\(^{1-3}\) and can be utilized in proton ceramic fuel cells (PCFC) and electrolyzer cells (PCEC)\(^{4,5}\) and electrochemical membrane reactors for steam methane reforming\(^{6}\) and dehydrogenation reactions.\(^{7}\) Zr-rich compositions display superior chemical stability in CO\(_2\)-containing atmospheres, although recent reports have shown some extent of surface reactivity also in BaZrO\(_3\) by accommodating Ba-deficiency in the subsurface region.\(^{8,9}\)

Grain boundaries in the polycrystalline BaZrO\(_3\)-based electrolytes have been found to exhibit reduced conductivity compared to bulk – a phenomenon ascribed to space-charge formation.\(^{10-16}\) Segregation of oxygen vacancies and protons – \(v_{\Omega}^{\text{tot}}\) and \(\text{OH}_3^+\) in Kröger–Vink notation\(^{17}\) – to the structural interface, \(i.e.,\) grain boundary core, yields a net positive charge of this region. Electro-neutrality is maintained by formation of space-charge regions adjacent to the grain boundary core. The increased grain boundary resistance can be associated with the locally depleted concentration of protons in the space-charge regions. Proton mobility may also be reduced at the structurally distorted grain boundary core.\(^{18}\)

Computational studies based on density functional theory (DFT) calculations and thermodynamic space-charge models have proven effective for understanding the fundamentals of coincident site lattice (CSL) type grain boundaries. In this respect, several studies on Y-doped BaZrO\(_3\) have shown that protons exhibit a particularly strong tendency for segregation to the grain boundary core.\(^{19-24}\) Similar interface properties have been obtained for BaZrO\(_3\) surfaces and heterointerfaces.\(^{25-28}\) Theoretically obtained space-charge potentials may exceed 1 V under the Mott–Schottky approximation, \(i.e.,\) constant concentration of the acceptor dopant across the interface. However, equilibration of the Y-concentration profile may significantly reduce the potential by segregation and accumulation in the space-charge regions,\(^{19,26,27}\) in line with potentials and concentration profiles obtained experimentally.\(^{29,30}\)

In comparison to cubic BaZrO\(_3\), proton segregation energies obtained for orthorhombic BaCeO\(_3\) have been found to be about half as exothermic for similar grain boundary structures.\(^{31,32}\) Lindman \textit{et al.} related the lower segregation energies in BaCeO\(_3\) to a higher stability of protons in the bulk region due to stronger hydrogen bond formation, rather than a property of the grain boundary structure.\(^{32}\)

In the present work, we further investigate space-charge formation at a \(\{0 2 1\}[1 0 0]\) tilt boundary in Y-doped BaCeO\(_3\). Particular emphasis is put on the multivalent nature of cerium which can attain a \(+3\) charge state, \(i.e.,\) Ce\(^{3+}\), with a polaron formation energy of \(-0.78\) eV relative to the conduction band.\(^{33}\) Under reducing conditions, the minority electron polarons may therefore accumulate in the core and/or space-charge regions and lower the space-charge potential.
2. Methodology

2.1 First-principles calculations

The DFT calculations were performed with projector augmented wave (PAW) pseudopotentials as implemented in VASP. The generalized gradient approximation functional due to Perdew, Burke, Ernzerhof (GGA-PBE) was used together with the Hubbard U correction according to the approach by Dudarev et al. (DFT+U). An effective on-site interaction parameter of \( U = 6 \) eV was used for Ce 4f in line with previous reports on BaCeO\(_3\) allowing for the localization of electrons as small Ce\(^{3+}\) polarons. The electrons explicitly treated as valence states were Ba (5s\(^2\) 5p\(^6\) 6s\(^2\)), Ce (5s\(^2\) 5p\(^6\) 5f\(^4\) 5d\(^6\) 6s\(^2\)) and O (2s\(^2\) 2p\(^4\)), while the Ce\(^{3+}\) (5s\(^2\) 5p\(^6\) 5f\(^5\) 5d\(^6\) 6s\(^2\)) pseudopotential was used for isolated Ce\(^{3+}\) polarons. For Ce\(^{3+}\) polarons associated with oxygen vacancies, initial structural relaxation was performed with the Ce\(^{3+}\) pseudopotential, and spin-polarization was employed for subsequent structural and electronic optimization. The plane wave energy cutoff was set to 400 eV and a Monkhorst-Pack \( k \)-point grid of 6x6x4 was used for the orthorhombic \( Pnma \) BaCeO\(_3\) unit cell (20 atoms). The relaxed cell parameters were \( a = 6.31 \) \( \text{Å} \), \( b = 8.88 \) \( \text{Å} \) and \( c = 6.30 \) \( \text{Å} \). Subsequent calculations were performed with fixed cell volume and shape, and the ionic positions were relaxed until the residual forces were smaller than 0.02 eV \( \text{Å}^{-1} \). The effective charge states of the point defects were imposed by adjusting the total number of electrons in the system.

2.2 Grain boundary structure

The (0 2 1) [1 0 0] symmetric tilt boundary was constructed as a stoichiometric cell with a stoichiometric interface plane comprising two formula units (Fig. 1). The axis perpendicular to the grain boundary was optimized with respect to interface energy in incremental steps of 0.1 \( \text{Å} \). Due to the periodic boundary conditions, the cell contained two identical interfaces which were separated by 11 Ba/Ce layers (22.2 \( \text{Å} \)). Defect calculations were performed in a supercell containing 480 atoms (12.63 \( \text{Å} \times 15.41 \) \( \text{Å} \times 44.45 \) \( \text{Å} \)) with \( \Gamma \)-point sampling. The difference in segregation energies obtained with 2x2x1 \( k \)-point sampling was within 1.5–4.5 meV for \( Y_{\text{Ce}} \) and \( \text{OH}_0^\bullet \) and up to 0.1 eV for \( \text{V}_0^\bullet \).

2.3 Space-charge model

Defect segregation energies, \( \Delta E_{\text{seg}} \), were calculated as the total energy difference for the defect between the interface sites and the bulk region within the same cell, i.e., 4 to 6 atomic layers from the closest interface. The considered defects were \( Y_{\text{Ce}}, \text{Ce}_{\text{Ce}}, \text{OH}_0^\bullet, \text{V}_0^\bullet \) and \( \left( \text{V}_0^\bullet \text{Ce}_{\text{Ce}} \right)^\bullet \). With several non-equivalent sites in the bulk region, the most stable defect site was used for calculating the segregation energy. For the interface, the most stable defect sites were fully relaxed in the supercell after initial calculations.

The defect segregation energies were used as input to a thermodynamic space-charge model based on a constant electro-chemical potential of all species across the interface and a global electroneutrality condition. A relative dielectric constant of 30 was used. Further details on the approach used in the present work can be found in ref. 19. The point defect concentrations in bulk were described according to a fixed Y-acceptor concentration of 0.10, and the hydration reaction which describes the relative concentrations of oxygen vacancies and protons

\[
\text{H}_2\text{O}(g) + \text{V}_0^\bullet + \text{O}_0 = 2\text{OH}_0^\bullet
\]  

(1)

The bulk concentrations of minority electrons and holes were taken from He et al. based on the electrical measurements of a BaCe\(_{0.85}\)Gd\(_{0.15}\)O\(_{3-\delta}\) single crystal as a function of oxygen partial pressure, \( P_{O_2} \). Table 1 lists the corresponding thermodynamic parameters used to obtain the bulk defect concentrations. The defects were generally treated within the dilute concentration limit while restrictions were imposed for the maximum defect concentrations in the core (cf. Section 3.2). An approach for treating...
concentrated solutions has been provided by Mebane et al. based on the Poisson–Cahn theory applied to CeO$_2$-based electrolytes.$^{44}$

### 3. Results and discussion

#### 3.1 Grain boundary structure

Fig. 1 illustrates the relaxed structure of the (0 2 1)[1 0 0] grain boundary. The interface contains two coordination environments that differ considerably from the bulk corner sharing octahedral coordination: trigonal prismatic coordination (Fig. 1b) and face-sharing octahedra (Fig. 1c). The optimized [1 0 2] axis corresponded to an expansion of 0.45 Å per grain boundary. The grain boundary energy was 0.036 eV Å$^{-2}$ (0.58 J m$^{-2}$), which is slightly lower than the energy obtained for the [1 2 0][0 0 1] boundary, 0.038 eV Å$^{-2}$. These grain boundaries exhibit different coordination environments around Ce6 and Ce7 (Fig. 1a) although the $Pnma$ [1 0 0] and [0 0 1] directions differ only in the type of octahedral tilting.

#### 3.2 Defect segregation energies

Fig. 2 shows the relaxed structures of oxygen vacancies at the most stable sites in the grain boundary core. The O1 site was found to be particularly favorable and vacancies introduced on neighboring sites relaxed to the O1 sites (Fig. 2c). The $Pnma$ [1 0 0] orientation of Ce relative to the doubly coordinated oxide ion sites in corner sharing octahedra (Table 2). In combination with Ce6 being coordinated to two O1, this may explain the particularly exothermic segregation energies for effectively positive defects to the O1 site. Neither $\nu_{O}^{0}$ or OH$_{O}$ was particularly stable associated with the trigonal prismatic or face-sharing oxide ion sites shown in Fig. 1. The oxygen vacancy segregation energies were essentially unchanged with accompanying polarons in the form of $\left( Ce_{Ce}^{+}\nu_{O}^{0} \right)$. Notably, the segregation energies of OH$_{O}$ to the O1 and O2 sites, −0.93 and −0.83 eV, respectively, were considerably more exothermic than the reported value for the [1 0 2][0 0 1] boundary, −0.51 eV.$^{32}$ The O1 site is under-coordinated to Ce relative to the doubly coordinated oxide ion sites in corner sharing octahedra (Table 2). In combination with Ce6 being coordinated to two O1, this may explain the particularly exothermic segregation energies for effectively positive defects to the O1 site. Neither $\nu_{O}^{0}$ or OH$_{O}$ was particularly stable associated with the trigonal prismatic or face-sharing oxide ion sites shown in Fig. 1. In the case of $Y_{Ce}$, the segregation energies were mostly positive except for the face-sharing Ce7 site. In comparison, Ce$_{Ce}$ polarons exhibited quite favorable segregation energies of −0.28 eV and −0.48 eV to the fully coordinated Ce4 and Ce7 sites relative to a fully coordinated bulk site. However, due to the strong binding energy of −0.44 eV for $\left( Ce_{Ce}^{+}\nu_{O}^{0} \right)$ in bulk,$^{33}$ the appropriate segregation energies for acceptor doped materials were taken as 0.16 eV and −0.04 eV for the Ce4 and Ce7 site, respectively. Furthermore, due to the favorable oxygen vacancy segregation energies adjacent to Ce5 and Ce6, the most relevant Ce$^{3+}$ polaron segregation energy was in the form of $\left( Ce_{Ce}^{+}\nu_{O}^{0} \right)$. The segregation energies of Ce$^{3+}$ were therefore 0.04 eV and 0.03 eV for Ce5 and Ce6, respectively, since segregation of $\nu_{O}^{0}$ was considered separately (Table 2). Association between polarons and protons was not considered due to their relatively low binding energy of −0.05 eV in bulk.$^{33}$

For the oxide ion sites in the core, upper limits on the defect occupancy were imposed based on the local coordination...
environment. In particular, protons associated with neighboring oxide ions would otherwise reside in the same region, e.g., O$_1$ and O$_2$ sites in Fig. 4. The total defect occupancy was limited to half for the O$_1$ and O$_3$ sites while full occupancy was allowed for the structurally isolated O$_2$ site.

### 3.3 Space-charge properties

Fig. 5 shows the calculated defect concentrations in the grain boundary core and as a function of distance in the space-charge region. The core concentrations are averages for the sites in Table 2. The core attains a net positive charge due to excess concentrations of v$_{O_1}^-$ and OH$_{O_1}^-$, and the resulting potential of 0.74 V extends about 1.5 nm into the space-charge regions. The core is predominated by v$_{O_1}^-$ due to the large exothermic segregation energy to the O$_1$ site (Table 2) resulting in a concentration of 0.50 site fraction according to the defined saturation limit. Protons compete for the same oxide ion sites and exhibit concentrations of 0.18, 0.16 and 4.3$\times10^{-4}$ site fraction for the O$_1$, O$_2$ and O$_3$ sites, respectively. Electron polarons display a quite significant accumulation in the space-charge region, and core concentration close to the bulk hole concentration despite the oxidizing atmospheric conditions.

### Table 2 Defect segregation energies for oxygen vacancies, protons, Y-acceptors and Ce$^{3+}$ for the sites noted in Fig. 1 with multiplicity and coordination number

<table>
<thead>
<tr>
<th>Defect</th>
<th>Site</th>
<th>Multiplicity</th>
<th>Coordination</th>
<th>$\Delta E_{\text{seg}}$/eV</th>
</tr>
</thead>
<tbody>
<tr>
<td>v$_{O_1}^-$</td>
<td>O$_1$</td>
<td>3</td>
<td>Ce</td>
<td>-1.66</td>
</tr>
<tr>
<td>v$_{O_2}^-$</td>
<td>O$_2$</td>
<td>1</td>
<td>2 Ce</td>
<td>-0.84</td>
</tr>
<tr>
<td>(v$_{O_1}^-$/Ce$^{3+}$)$_O$</td>
<td>O$_1$/Ce$_6$</td>
<td>3</td>
<td>1 Ce</td>
<td>-1.63</td>
</tr>
<tr>
<td>(v$_{O_2}^-$/Ce$^{3+}$)$_O$</td>
<td>O$_2$/Ce$_5$</td>
<td>1</td>
<td>2 Ce</td>
<td>-0.80</td>
</tr>
<tr>
<td>OH$_{O_1}^-$</td>
<td>O$_1$</td>
<td>3</td>
<td>1 Ce</td>
<td>-0.93</td>
</tr>
<tr>
<td>OH$_{O_2}^-$</td>
<td>O$_2$</td>
<td>1</td>
<td>2 Ce</td>
<td>-0.83</td>
</tr>
<tr>
<td>OH$_{O_3}^-$</td>
<td>O$_3$</td>
<td>4</td>
<td>2 Ce</td>
<td>-0.47</td>
</tr>
<tr>
<td>Y$_{Ce}/Ce^{3+}$</td>
<td>Ce$_4$</td>
<td>1</td>
<td>6 O</td>
<td>0.16/0.28</td>
</tr>
<tr>
<td>Y$_{Ce}/Ce^{3+}$</td>
<td>Ce$_5$</td>
<td>2</td>
<td>6 O</td>
<td>0.14/0.17</td>
</tr>
<tr>
<td>Y$_{Ce}/Ce^{3+}$</td>
<td>Ce$_6$</td>
<td>1</td>
<td>6 O</td>
<td>0.56/0.31</td>
</tr>
<tr>
<td>Y$_{Ce}/Ce^{3+}$</td>
<td>Ce$_7$</td>
<td>2</td>
<td>6 O</td>
<td>-0.08/0.48</td>
</tr>
</tbody>
</table>

**Fig. 4** Relaxed structure of protons associated with the O$_1$ (a), O$_2$ (b), and O$_3$ (c) oxide ions in the grain boundary core, including the bond length to the neighboring oxide ion.

**Fig. 5** Defect concentrations and potential in the grain boundary core and as a function of distance in the space-charge region. The core concentrations are averages for the sites in Table 2.
the core is saturated by OH$_\text{O}$ on the O1 and O2 sites, while the OH$_\text{O}$ site fraction was 3.8 × 10$^{-2}$ for the O3 site. The core gradually dehydrates with increasing temperature, which results in a higher potential due to the higher core charge as OH$_\text{O}$ is exchanged with v$^\text{**}$. In contrast to several studies on BaZrO$_3$ grain boundaries, the core becomes mainly dehydrated at a lower temperature (805 K) than bulk (1000 K). The space-charge potential exhibits a maximum at about 873 K as the O1 site becomes saturated by v$^\text{**}$ while the total core charge is reduced at higher temperatures since the concentration of OH$_\text{O}$ becomes lower on the O2 and O3 sites. The concentration of the electronic defects in the core remains negligible in terms of the overall core charge.

Fig. 7 shows the core defect concentrations and space-charge potential as a function of oxygen partial pressure from highly reducing to highly oxidizing conditions at 873 K. Under the most reducing conditions, the electron polaron concentration in the core becomes significant in terms of charge compensation, i.e., within one order of magnitude of Y$_\text{Ce}^3+$, and the space-charge potential is lowered. Nevertheless, the lower core potential increases the stability of the effectively positive defects and the concentration of OH$_\text{O}$ thereby increases on the O2 and O3 sites below $p_{O_2} = 10^{-18}$ bar as the electron concentration in the core increases.

At higher $p_{O_2}$, the space-charge potential remains fairly constant and the concentration of electron polarons in the core follows the same functional dependency as in bulk, i.e., $p_{O_2}^{-1/4}$. Despite a bulk hole concentration of 10$^{-4}$ per mole BaCeO$_3$ at $p_{O_2} = 100$ bar, depletion of holes in the space-charge region does not affect the space-charge potential. This is because depletion of minority defects in the space-charge region cannot contribute to charge compensation of the core.

The potential for ionic conduction along the grain boundary core can be assessed based on the defect concentrations and connectivity between the relevant core sites. In this respect, the O1 sites may provide a conduction path for oxide ions (Fig. 2a), while proton conduction may proceed along O1 and/or O2 sites (Fig. 4a and c) depending on the level of hydration. The specific activation energies of migration are also required for a complete assessment of grain boundary conduction. However, the contribution from the grain boundary core to the overall ionic conductivity of the polycrystalline material can be expected to be negligible since the bulk exhibits relatively high ionic conductivities. On the other hand, significant ionic conductivity along grain boundaries may become evident in materials with relatively low bulk ionic conductivities.

In electrolyte materials such as Y-doped BaCeO$_3$, grain boundary conduction may therefore only become evident for species which exhibit comparatively low conductivities in bulk, e.g., cations and electronic charge carriers. Due to the positively charged core, the present work has shown significant accumulation of electron polarons in the core and space-charge regions, particularly under reducing conditions. The electron conductivity along the grain boundary can be expected to increase accordingly, while the contribution from the polarons in the core also depends on their mobility relative to the bulk which exhibits an activation energy of about 0.3 eV.$^{33}$ In this respect, experimental evidence of n-type grain boundary conduction has been reported for Y-doped BaZrO$_3$ under strongly reducing conditions, e.g., $p_{O_2} < 10^{-30}$. Due to the higher reducibility of Ce relative to Zr, this effect can be expected to be even more prominent in Ce-containing compositions. Electron conduction along grain boundaries may contribute to non-faradaic electronic leak paths in electrochemical devices based on these electrolyte materials.

4. Conclusion

Space-charge formation at the (0 2 1)[1 0 0] symmetric tilt grain boundary of Y-doped BaCeO$_3$ was determined to originate from significant segregation of protons and oxygen vacancies. These defects compete for some of the most stable defect sites in the core which could be saturated by oxygen vacancies or protons depending on temperature and water vapor pressure. Ce$^{3+}$ polarons were almost equally stabilized adjacent to oxygen vacancies in the bulk and grain boundary core, and their tendency to accumulate in the core was therefore mainly given by the core potential. The space-charge potential increased from 0.45 V to 0.75 V upon
dehydration of the core mainly due to the higher effective charge of oxygen vacancies compared to protons. Accumulation of minority electrons in the core and space-charge regions was quite substantial and increased with increasing temperature and decreasing $p_{O_2}$. However, the influence of electrons on the space-charge potential was evident only under considerably reducing conditions, e.g., $p_{O_2} < 10^{-16}$ bar at 873 K.

Conflicts of interest

There are no conflicts to declare.

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